Thyristor-Thyristor Module, 460 Amps

Features

- Improved glass passivation for high reliability
- Exceptional stability at high temperatures
- High di/dt and dv/dt capabilities
- Low thermal resistance

Voltage Ratings (T_A = 25°C, unless otherwise noted)

Type number	Voltage Code	V_{RRM}, Maximum repetitive peak reverse voltage (V)	V_{RSM}, Maximum non-repetitive peak reverse voltage (V)	V_{DRM}, Maximum repetitive peak off-state voltage (V)	I_{RRM}, Maximum reverse leakage current @ T_{JMAX} (mA)
NTT570	60	600	700	600	max. 220
	80	800	900	800	
	100	1000	1100	1000	
	120	1200	1300	1200	
	140	1400	1500	1400	
	160	1600	1700	1600	
	180	1800	1900	1800	

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Values	Units
Maximum average forward current @ T_J = 85°C	$I_{T(AV)}$	570	A
Maximum average RMS forward current	$I_{T(RMS)}$	895	A
Maximum non-repetitive surge current	I_{TSM}	19000	A
Maximum I^2t for fusing	I^2t	1805000	A^2s
Forward voltage drop	V_{TM}	max. 1.45	V
Critical rate of rise of on-state current	di/dt	max. 250	A/µs
Critical rate of rise of off-state voltage	dv/dt	max. 1000	V/µs
Gate current required to trigger	I_{GT}	min. 200	mA
Gate voltage required to trigger	V_{GT}	min. 3	V
Maximum holding current	I_H	150	mA
Maximum latching current	I_L	300	mA
Isolation voltage	V_{ISO}	3000	V

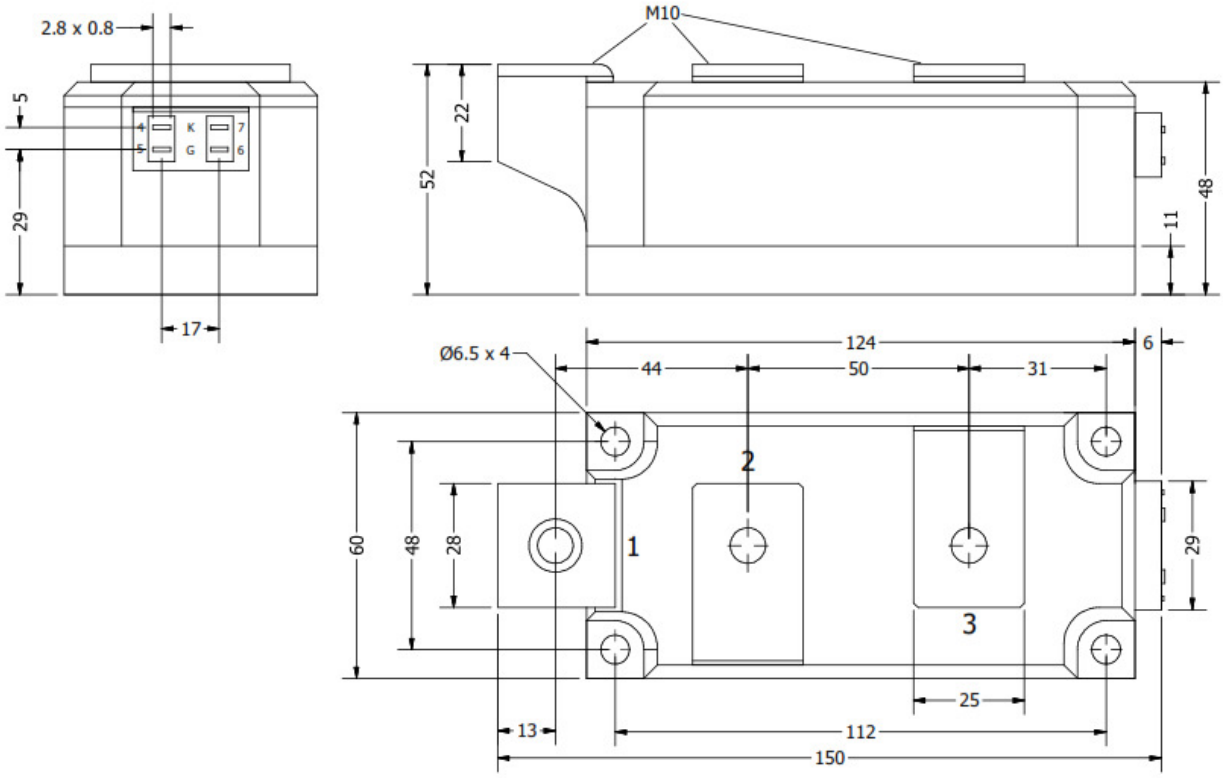
Thermal & Mechanical Specifications (T_A = 25°C unless otherwise noted)

Parameter		Symbol	Values	Units
Operating junction temperature range		T_J	-40 to +135	°C
Storage temperature		T_{stg}	-40 to +125	°C
Thermal resistance, junction to case		$R_{th(JC)}$	0.06	°C/W
Mounting torque	to heatsink	F	5 ± 15%	Nm
	to terminals		10 ± 15%	
Weight		W	1500	g

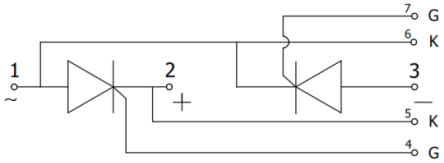
D-95, Sector 63, Noida – 201301, India • Tel: 0120-4205450 • Fax: 0120-4273653
sales@nainasemi.com • www.nainasemi.com

Package Outline

(All dimensions in mm)



Circuit Configuration

Circuit Description	Configuration Code	Circuit Drawing
Series Connection (doubler circuit)	N	

Ordering Table

NTT	*570*	*N*	*160*
1	2	3	4

1 – Power Module
- > DD = Diode-Diode
- > TD = Thyristor-Diode
- > TT = Thyristor-Thyristor

2 – Current Rating = $I_{T(AV)}$
3 – Circuit Configuration (see Table)
4 – Voltage Code (see Voltage Ratings table)

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